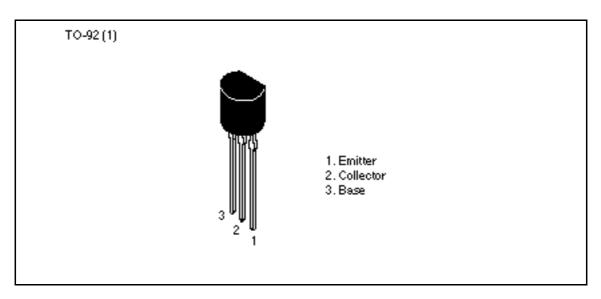
Silicon NPN Epitaxial

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Application

- Low frequency amplifier
- Complementary pair with 2SA1025, 2SA1081 and 2SA1082

Outline





Absolute Maximum Ratings (Ta = 25° C)

Item	Symbol	2SC2396	2SC2543	2SC2544	Unit
Collector to base voltage	V _{CBO}	60	90	120	V
Collector to emitter voltage	V _{CEO}	60	90	120	V
Emitter to base voltage	V_{EBO}	5	5	5	V
Collector current	I _c	100	100	100	mA
Emitter current	Ι _Ε	-100	-100	-100	mA
Collector power dissipation	Pc	400	400	400	mW
Junction temperature	Tj	150	150	150	°C
Storage temperature	Tstg	-55 to +150	-55 to +150	-55 to +150	°C

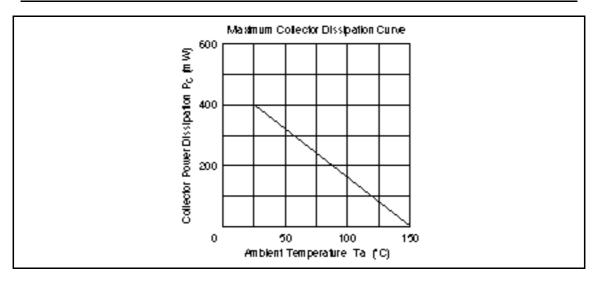
Electrical Characteristics (Ta = 25°C)

		2SC2	2396		2SC2543		2SC2544					
Item	Symbol	Min	Тур	Max	Min	Тур	Мах	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	V _{(BR)CBO}	60	_	_	90	_	-	120	_	_	V	$I_{c} = 10 \ \mu A, \ I_{E} = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	60	—	—	90	—	_	120	_	—	V	I _c = 1 mA, R _{BE} =
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	—	—	5	—	_	5	_	—	V	$I_{\rm E} = 10 \ \mu {\rm A}, \ I_{\rm C} = 0$
Collector cutoff current	I _{CBO}	—	—	0.1	—	—	0.1		—	0.1	μA	$V_{CB} = 50 \text{ V}, \text{ I}_{E} = 0$
Emitter cutoff current	I_{EBO}	—		0.1	_	_	0.1		_	0.1	μA	$V_{EB} = 2 \text{ V}, \text{ I}_{C} = 0$
DC current transfer ratio	h _{FE} *1	250	_	1200	250	_	1200	250	_	800		$V_{CE} = 12 \text{ V},$ $I_C = 2 \text{ mA}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	_	_	0.2	_	_	0.2	_	_	0.2	V	$I_{c} = 10 \text{ mA},$ $I_{B} = 1 \text{ mA}$
Base to emitter voltage	V_{BE}	_	0.6	_	_	0.6	_	_	0.6	_	V	$V_{CE} = 12 \text{ V},$ $I_C = 2 \text{ mA}$
Gain bandwidth product	f _T	_	90	_	_	90	_	_	90	_	MHz	$V_{CE} = 12 \text{ V},$ $I_C = 2 \text{ mA}$
Collector output capacitance	Cob	_	3.0	_	_	3.0	_	_	3.0	_	pF	$V_{CB} = 10 \text{ V}, \text{ I}_{E} = 0,$ f = 1 MHz
Note: 1. The 2SC2396, 2SC2543 and 2SC2544 are grouped by h _{FE1} as follows.												
	D		Е		F							
2SC2396, 2SC2543	250 to	500	400	to 800) 60)0 to 1	200					

2SC2396, 2SC2543	250 to 500	400 to 800	600 to 1200
2SC2544	250 to 500	400 to 800	_

See characteristic curves of 2SC2545, 2SC2546 and 2SC2547.

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